

### **Features**

- · Rugged and Reliable
- · Lead Free Product is Acquired
- High Dense Cell Design for Extremely Low R<sub>DS(ON)</sub>
- · Epoxy Meets UL 94 V-0 Flammability Rating
- · Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (Note 1)
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

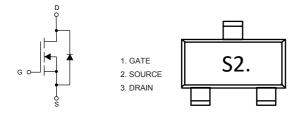
# **Maximum Ratings**

- Operating Junction Temperature Range: -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 100°C/W Junction to Ambient

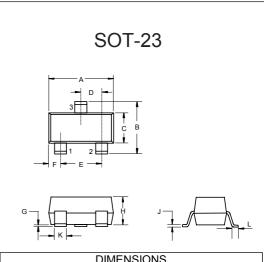
Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V <sub>DS</sub>	20	V
Gate-Source Voltage	V <sub>GS</sub>	±8	V
Drain Current-Continuous	I <sub>D</sub>	3.0	Α
Drain Current-Pulsed <sup>(Note 2)</sup>	I <sub>DM</sub>	10	Α
Power Dissipation	P <sub>D</sub>	1.25	W

Note: 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

# **Internal Structure and Marking Code**

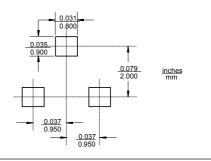


# N-Channel Enhancement Mode Field Effect Transistor



DIMENSIONS					
DIM	INC	INCHES		M	NOTE
DIIVI	MIN	MAX	MIN	MAX	NOTE
Α	0.110	0.120	2.80	3.04	
В	0.083	0.104	2.10	2.64	
С	0.047	0.055	1.20	1.40	
D	0.034	0.041	0.85	1.05	
E	0.067	0.083	1.70	2.10	
F	0.018	0.024	0.45	0.60	
G	0.0004	0.006	0.01	0.15	
Н	0.035	0.043	0.90	1.10	
J	0.003	0.007	0.08	0.18	
K	0.012	0.020	0.30	0.51	
L	0.007	0.020	0.20	0.50	

#### **Suggested Solder Pad Layout**





## ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

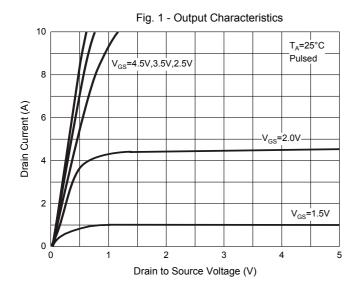
Parameter	Symbol	Test conditions	Min	Тур	Max	Unit	
Static Characteristics			·				
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =10μA	20			V	
Gate-Threshold Voltage(Note 4)	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA	0.65		1.2	V	
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =± 8V, V <sub>DS</sub> =0V			±100	nA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =20V, V <sub>GS</sub> =0V			1	μA	
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =3.6A		55	72	mΩ	
Drain-Source On-Resistance <sup>(Note 4)</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> =2.5V, I <sub>D</sub> =3.1A		82	110		
Forward Transconductance(Note 4)	g <sub>FS</sub>	V <sub>DS</sub> =5V, I <sub>D</sub> =3.6A		8.5		S	
Dynamic Characteristics(Note 5)							
Input Capacitance	C <sub>iss</sub>			237			
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> =10V,V <sub>GS</sub> =0V, f=1MHz		120		pF	
Reverse Transfer Capacitance	C <sub>rss</sub>			45			
Switching Characteristics(Note 5)							
Turn-On Delay Time	t <sub>d(on)</sub>			23	45		
Turn-On Rise Time	t <sub>r</sub>	$V_{DD}$ =10V, $V_{GS}$ =4.5V, $I_{D}$ =3.6A, $R_{GEN}$ =6 $\Omega$		11	30		
Turn-Off Delay Time	t <sub>d(off)</sub>	1D-3.0A, N <sub>GEN</sub> -012		34	70	ns	
Turn-Off Fall Time	t <sub>f</sub>			36	70		
Total Gate Charge	Qg			6	10		
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =10V, V <sub>GS</sub> =4.5V, I <sub>D</sub> =3.6A		1.4		nC	
Gate-Drain Charge	$Q_{gd}$			1.8			
Drain-Source Diode Character	ristics and	d Maximum Ratings		ı	I		
Diode Forward Voltage <sup>(Note3)</sup>	V <sub>SD</sub>	V <sub>GS</sub> =0V, I <sub>S</sub> =0.94A			1.2	V	
Drain-Source Diode Forward Current(Note2)	I <sub>S</sub>				0.94	А	

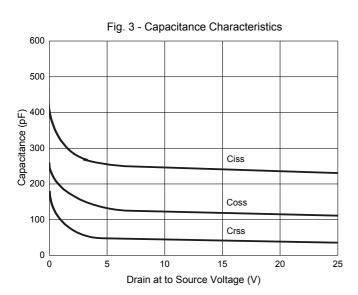
## Notes:

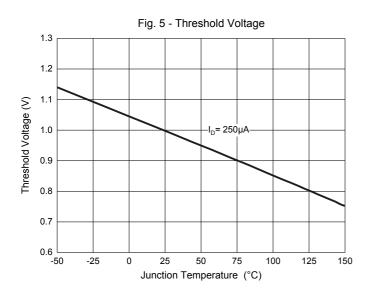
- 2. Repetitive Rating : Pulse Width limited By Maximum Junction Temperature.
- 3. Surface Mounted on FR4 Board, t < 10 sec.
- 4. Pulse Test : Pulse Width < 300µs, Duty Cycle < 2%.
- 5. Guaranteed By Design, Not Subject to Production Testing.

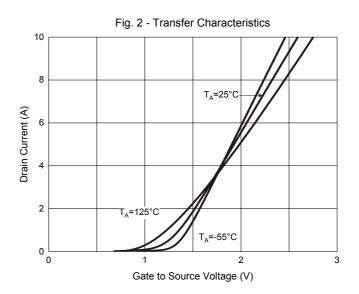


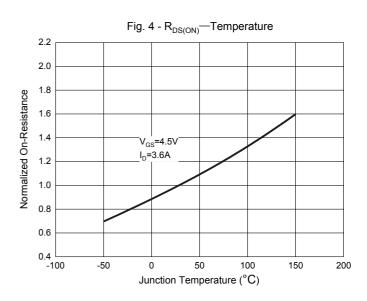
## **Curve Characteristics**

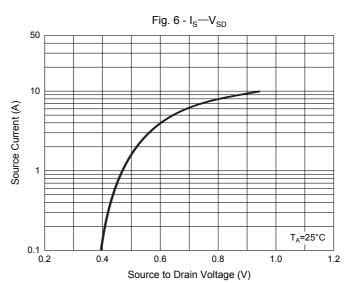














## **Ordering Information**

Device	Packing	
Part Number-TP	Tape&Reel:3Kpcs/Reel	

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